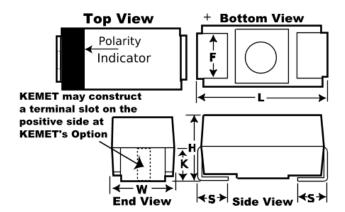


T495B336K006ZTE600

Obsolete

Tantalum, MnO2 Tantalum, 33 uF, 10%, 6.3 VDC, SMD, Molded, Low ESR, Surge Robust, 600 mOhms, 3528, 2.1mm



Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
S	0.7mm +/-0.3mm
F	2.2mm +/-0.1mm
K	1.4mm TYP

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

General Information		
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, Molded, Low ESR, Surge Robust	
Features	Low ESR, Surge Robust	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Notes	Obsolete. Old Part Number [Obsolete] Was B45197A1336K209.	

Specifications	,
Capacitance	33 uF
Capacitance Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.6 Ohms (100kHz)
Ripple Current	350 mAmps (25C), 315 mAmps (85C), 140 mAmps (125C)
Leakage Current	2.1uA

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.